

CMKD6263DO

SURFACE MOUNT SILICON  
DUAL OPPOSING  
HIGH VOLTAGE  
SCHOTTKY DIODE



www.centrasemi.com

**DESCRIPTION:**

The CENTRAL SEMICONDUCTOR CMKD6263DO contains two (2) galvanically isolated, high voltage, low  $V_F$  silicon Schottky diodes with an opposing Anode/Cathode configuration, epoxy molded in a SOT-363 surface mount package. This device has been designed for fast switching applications requiring a low forward voltage drop.

**MARKING CODE: 63D**



SOT-363 CASE

**FEATURES:**

- Dual Opposing (DO) Schottky Diodes
- High Voltage (70V)
- Low Forward Voltage
- Galvanically Isolated

**MAXIMUM RATINGS:** ( $T_A=25^\circ\text{C}$ )

Peak Repetitive Reverse Voltage  
Continuous Forward Current  
Peak Forward Surge Current,  $t_p=1.0\text{s}$   
Power Dissipation  
Operating and Storage Junction Temperature  
Thermal Resistance

SYMBOL		UNITS
$V_{RRM}$	70	V
$I_F$	15	mA
$I_{FSM}$	50	mA
$P_D$	250	mW
$T_J, T_{stg}$	-65 to +150	$^\circ\text{C}$
$\theta_{JA}$	500	$^\circ\text{C/W}$

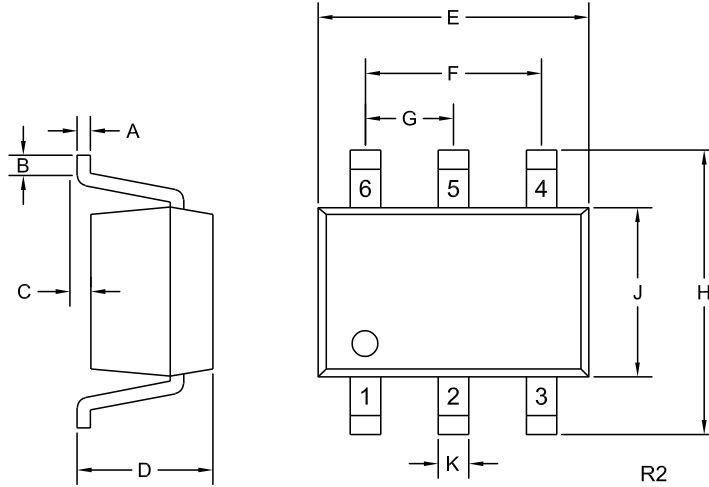
**ELECTRICAL CHARACTERISTICS PER DIODE:** ( $T_A=25^\circ\text{C}$  unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
$I_R$	$V_R=50\text{V}$		10	200	nA
$BV_R$	$I_R=10\mu\text{A}$	70			V
$V_F$	$I_F=1.0\text{mA}$		395	410	mV
$C_J$	$V_R=0, f=1.0\text{MHz}$			2.0	pF
$t_{rr}$	$I_R=I_F=10\text{mA}, I_{rr}=1.0\text{mA}, R_L=100\Omega$			5.0	ns

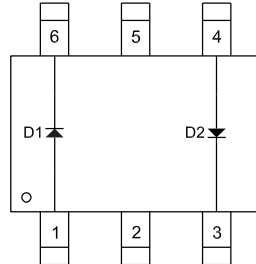
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**SOT-363 CASE - MECHANICAL OUTLINE**



**PIN CONFIGURATION**



**LEAD CODE:**

- 1) Anode D1
- 2) NC
- 3) Cathode D2
- 4) Anode D2
- 5) NC
- 6) Cathode D1

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**DIMENSIONS**

SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.004	0.010	0.10	0.25
B	0.005	-	0.12	-
C	0.000	0.004	0.00	0.10
D	0.031	0.043	0.80	1.10
E	0.071	0.087	1.80	2.20
F	0.051		1.30	
G	0.026		0.65	
H	0.075	0.091	1.90	2.30
J	0.043	0.055	1.10	1.40
K	0.006	0.012	0.15	0.30

SOT-363 (REV: R2)

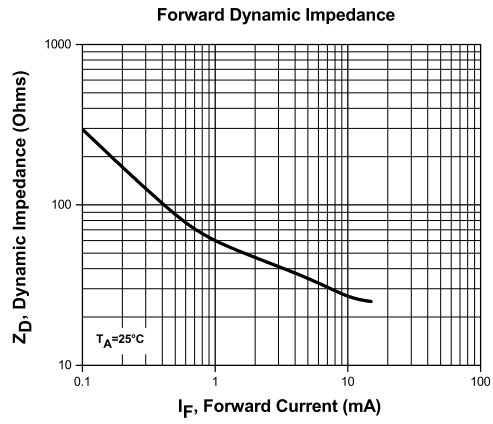
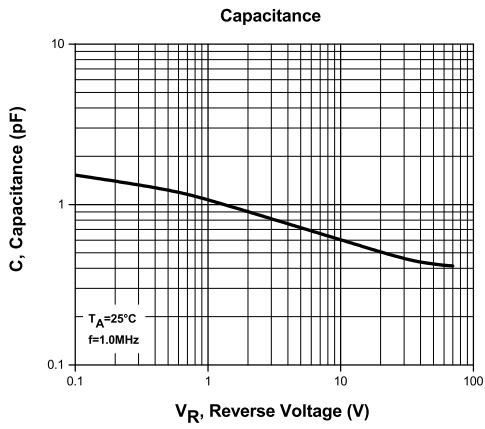
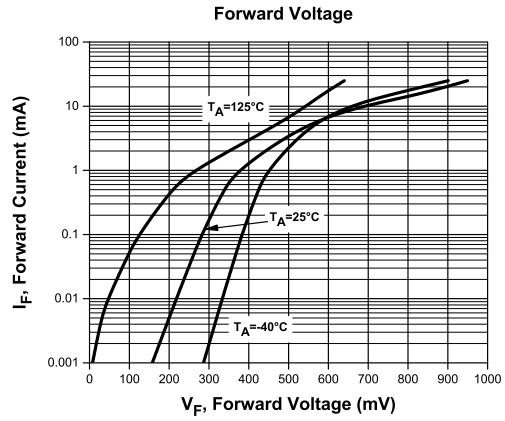
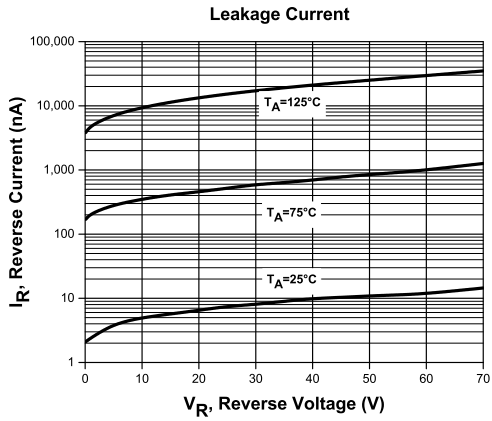
R4 (11-December 2015)

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TYPICAL ELECTRICAL CHARACTERISTICS



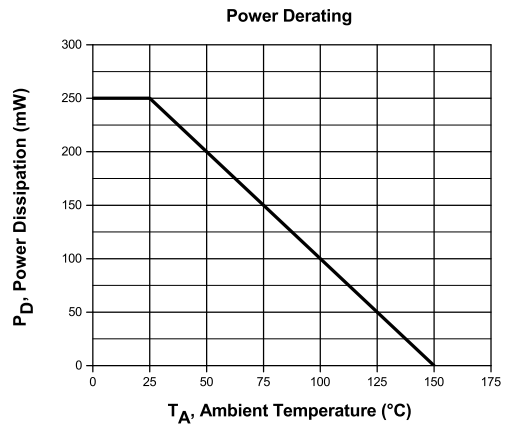
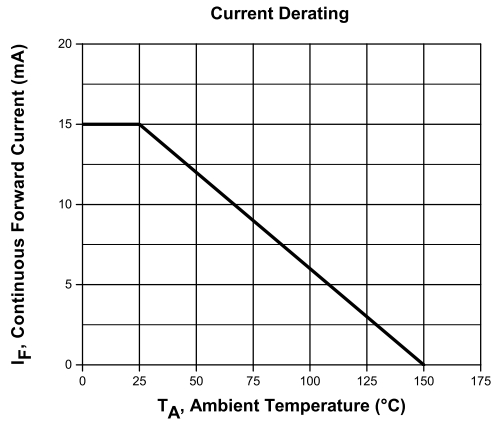
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### TYPICAL ELECTRICAL CHARACTERISTICS



R4 (11-December 2015)

## OUTSTANDING SUPPORT AND SUPERIOR SERVICES



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### PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options
- Custom bar coding for shipments
- Custom product packing

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### DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2<sup>nd</sup> day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities
- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- Application and design sample kits
- Custom product and package development

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### CONTACT US

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